

SEMICONDUCTOR TECHNICAL DATA

KMB050N60P

N CHANNEL MOS FIELD EFFECT TRANSISTOR

General Description

This planar stripe MOSFET has better characteristics, such as fast switching time, low on resistance, low gate charge and excellent avalanche characteristics. It is mainly suitable for active power factor correction, electronic lamp ballasts based on half bridge topology and switching mode power supplies.

FEATURES



2006. 4. 24 Revision No : 1